

1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

ABSOLUTE MAXIMUM RATINGS

V_{CC} to GND-0.3V to +7V
 SHDN to GND-0.3V to (V_L + 0.3V)
 I/O V_L to GND-0.3V to (V_L + 0.3V)
 V_L, I/O V_{CC} to GND-0.3V to (V_{CC} + 0.3V)
 Short-Circuit Duration: I/O V_L, I/O V_{CC} to GNDContinuous

Continuous Power Dissipation (T_A = +70°C)
 SC70 (derate 3.1mW/°C above +70°C)245mW
 6-Pin μ DFN (derate 2.1mW/°C above +70°C)168mW
 Operating Temperature Range-40°C to +85°C
 Storage Temperature Range-65°C to +150°C
 Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{CC} = +2.5V to +5.5V, V_L = +1.6V to +5.5V (Note 1), GND = 0; I/O V_L, I/O V_{CC} unconnected; T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLIES						
V _L Supply Range	V _L	(Note 1)	1.6		5.5	V
V _{CC} Supply Range	V _{CC}		2.5		5.5	V
Supply Current from V _{CC}	I _{QVCC}			70	100	μ A
Supply Current from V _L	I _{QVL}			5	100	μ A
V _{CC} Shutdown Supply Current		SHDN = GND, T _A = +25°C, MAX3371		0.03	1	μ A
V _L Shutdown Supply Current		SHDN = GND, T _A = +25°C, MAX3371		0.03	1	μ A
Three-State Output Leakage Current		I/O V _L , I/O V _{CC} ; SHDN = GND, T _A = +25°C, MAX3371		0.02	1	μ A
LOGIC LEVEL THRESHOLDS						
I/O V _L Input-Voltage High Threshold	V _{IHL}				V _L - 0.2	V
I/O V _L Input-Voltage Low Threshold	V _{ILL}		0.15			V
I/O V _{CC} Input-Voltage High Threshold	V _{IHC}				V _{CC} - 0.4	V
I/O V _{CC} Input-Voltage Low Threshold	V _{ILC}		0.2			V
I/O V _L Output-Voltage High	V _{OHL}	I/O V _L sink current = 20 μ A, I/O V _{CC} \geq V _{CC} - 0.4V (Note 3)	2/3 \times V _L			V
I/O V _L Output-Voltage Low	V _{OLL}	I/O V _L sink current = 1mA, I/O V _{CC} \leq 0.2V (Note 3)		0.4		V
I/O V _{CC} Output-Voltage High	V _{OHC}	I/O V _{CC} source current = 20 μ A, I/O V _L \geq V _L - 0.2V (Note 3)	2/3 \times V _{CC}			V
I/O V _{CC} Output-Voltage Low	V _{OLC}	I/O V _{CC} sink current = 1mA, I/O V _L \leq 0.15V (Note 3)		0.4		V
SHDN Input-Voltage High	V _{IH-SHDN}		2/3 \times V _L			V
SHDN Input-Voltage Low	V _{IL-SHDN}	V _L \geq +1.8V		0.4		V
		V _L \geq +1.6V		0.2		

1μA, 2Mbps, Low-Voltage Level Translators in SC70 and μDFN

MAX3370/MAX3371

ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = +2.5V to +5.5V, V_L = +1.6V to +5.5V (Note 1), GND = 0; I/O V_L, I/O V_{CC} unconnected; T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
TIMING CHARACTERISTICS (R _{LOAD} = 1MΩ, V _{CC} = +2.5V, V _L = +1.6V, I/O test signal rail-to-rail, unless otherwise noted, Figure 1) (Note 3)						
I/O V _{CC} Rise Time (Note 4)	t _{RVCC}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			100	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			200	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	
I/O V _{CC} Fall Time (Note 4)	t _{FVCC}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			200	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	
I/O V _L Rise Time (Note 4)	t _{RVL}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			100	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			200	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	
I/O V _L Fall Time (Note 4)	t _{FVL}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			200	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	
HIGH-to-LOW Transition Propagation Delay (Driving I/O V _L)	t _{PD-VCC-HL}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			200	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	
LOW-to-HIGH Transition Propagation Delay (Driving I/O V _L)	t _{PD-VCC-LH}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			200	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			400	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			800	
HIGH-to-LOW Transition Propagation Delay (Driving I/O V _{CC})	t _{PD-VL-HL}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			200	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	
LOW-to-HIGH Transition Propagation Delay (Driving I/O V _{CC})	t _{PD-VL-LH}	C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			200	ns
		C _{LOAD} = 50pF, data rate = 1Mbps			400	
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			800	
HIGH-to-LOW Transition Propagation Delay Device-to-Device Skew (Driving I/O V _L)		C _{LOAD} = 10pF, data rate = 2Mbps (Note 3)		2		ns
		C _{LOAD} = 50pF, data rate = 1Mbps		4		
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive		5		

1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = +2.5V to +5.5V, V_L = +1.6V to +5.5V (Note 1), GND = 0; I/O V_L , I/O V_{CC} unconnected; T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
LOW-to-HIGH Transition Propagation Delay Device-to-Device Skew (Driving I/O V_L)		C_{LOAD} = 10pF, data rate = 2Mbps (Note 3)		5		ns
		C_{LOAD} = 50pF, data rate = 1Mbps		8		
		C_{LOAD} = 30pF, data rate = 500kbps, open-drain drive		80		
HIGH-to-LOW Transition Propagation Delay Device-to-Device Skew (Driving I/O V_{CC})		C_{LOAD} = 10pF, data rate = 2Mbps (Note 3)		2		ns
		C_{LOAD} = 50pF, data rate = 1Mbps		4		
		C_{LOAD} = 30pF, data rate = 500kbps, open-drain drive		5		
LOW-to-HIGH Transition Propagation Delay Device-to-Device Skew (Driving I/O V_{CC})		C_{LOAD} = 10pF, data rate = 2Mbps (Note 3)		7		ns
		C_{LOAD} = 50pF, data rate = 1Mbps		8		
		C_{LOAD} = 30pF, data rate = 500kbps, open-drain drive		50		
Maximum Data Rate		C_{LOAD} = 10pF (Note 5)	2	3		Mbps
		C_{LOAD} = 50pF	1	2		
		C_{LOAD} = 30pF, open-drain drive	0.5	1		

Note 1: V_L must always be less than or equal to V_{CC} .

Note 2: All units are 100% production tested at T_A = +25°C. Limits over the operating temperature range are guaranteed by design and not production tested.

Note 3: Tested only at worst case: V_{CC} = +2.5V, V_L = +1.6V.

Note 4: 10% to 90%.

Note 5: Guaranteed by correlation to C_{LOAD} = 50pF.

1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

MAX3370/MAX3371

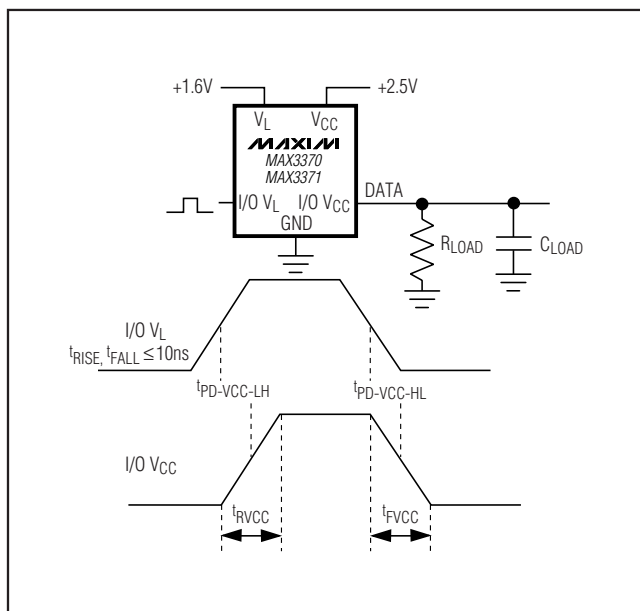


Figure 1a. Rail-to-Rail Driving I/O V_L

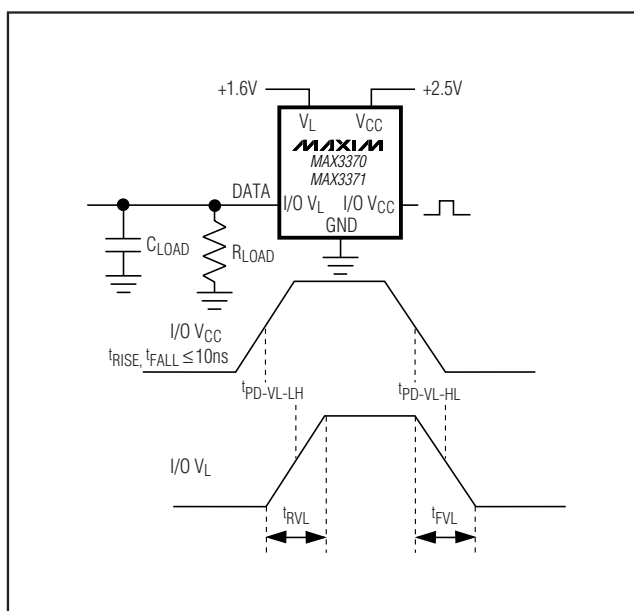


Figure 1b. Rail-to-Rail Driving I/O V_{CC}

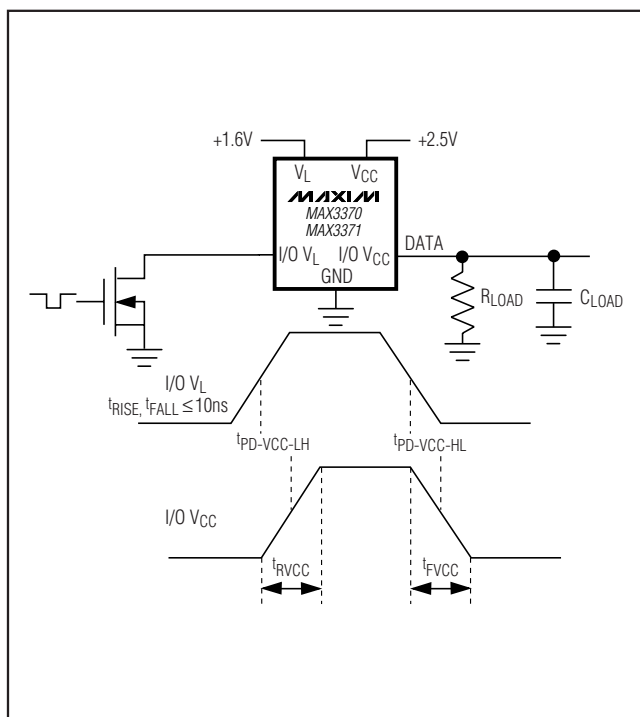


Figure 1c. Open-Drain Driving I/O V_L

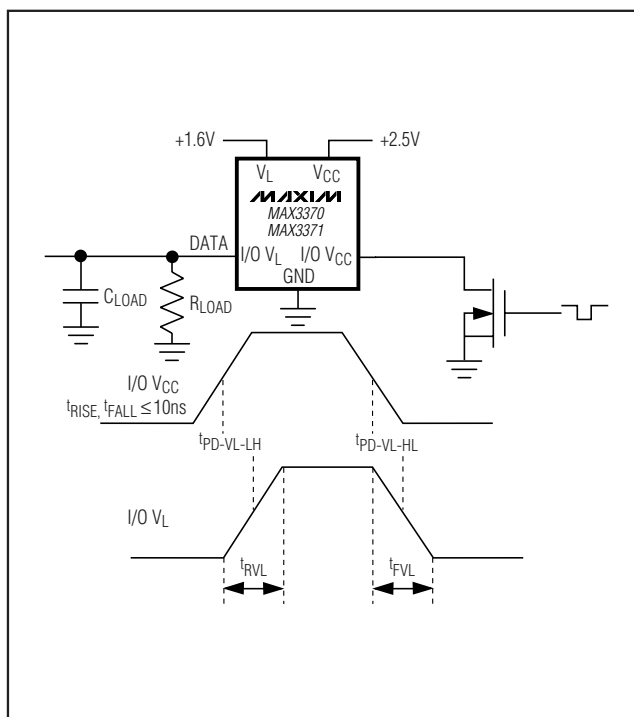
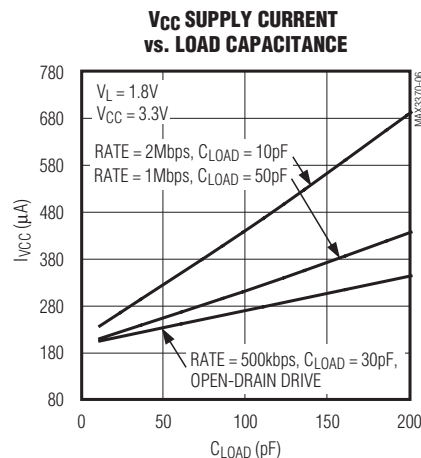
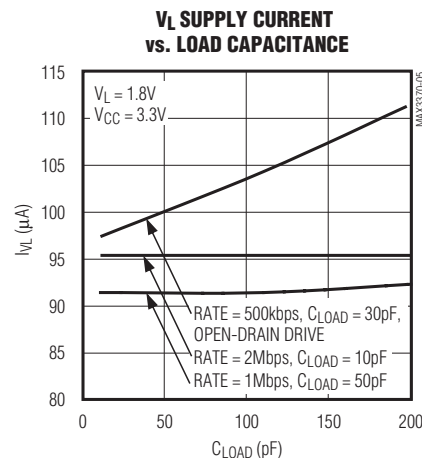
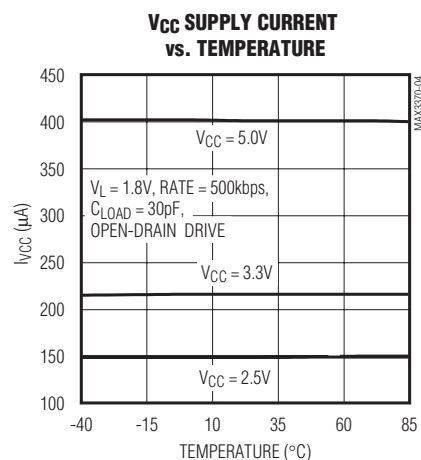
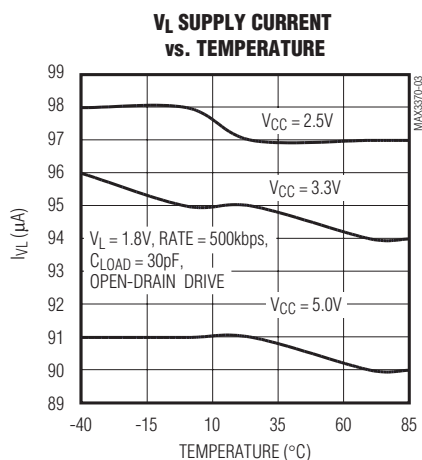
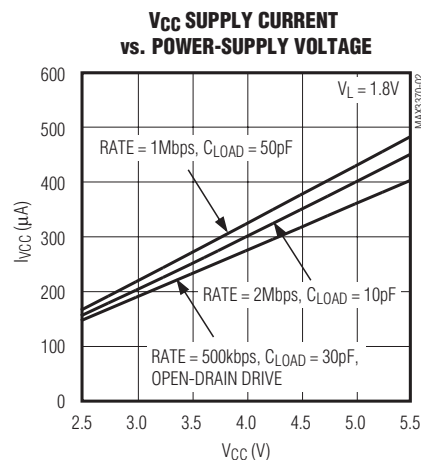
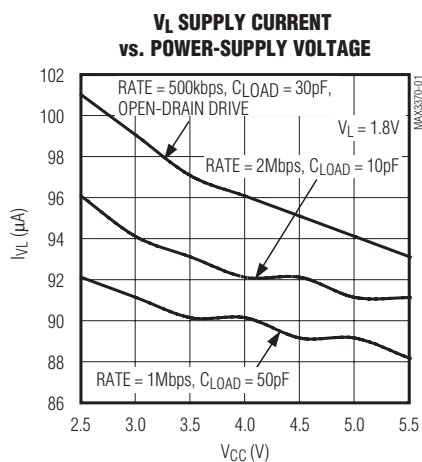


Figure 1d. Open-Drain Driving I/O V_{CC}

1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

Typical Operating Characteristics

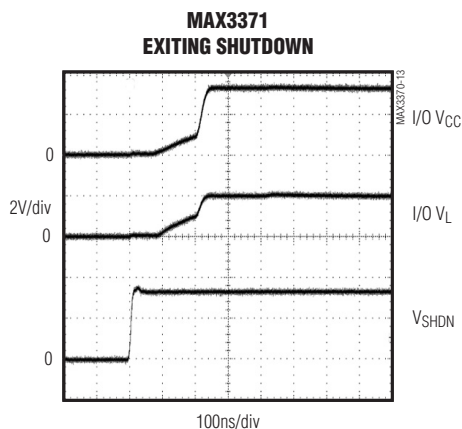
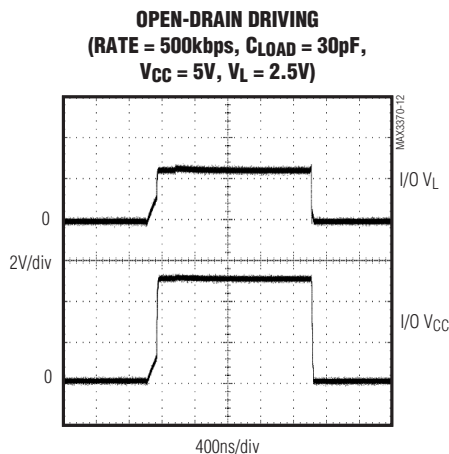
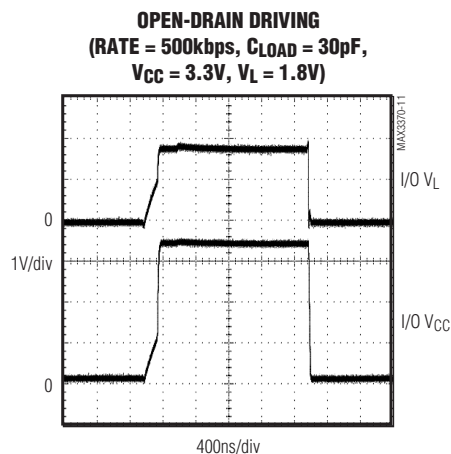
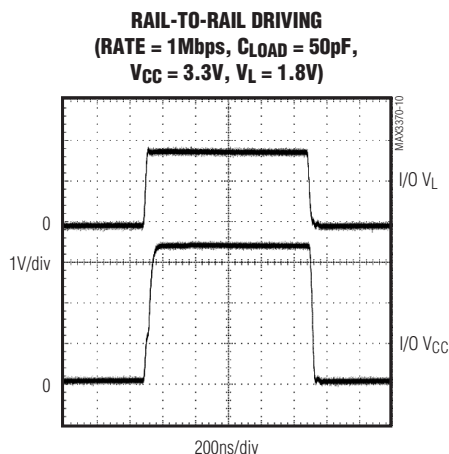
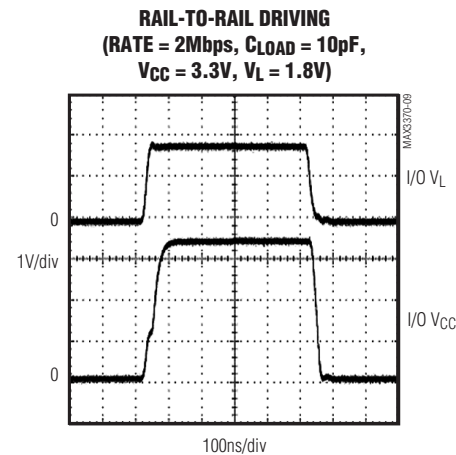
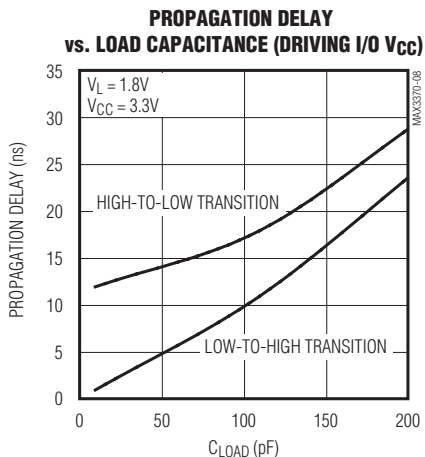
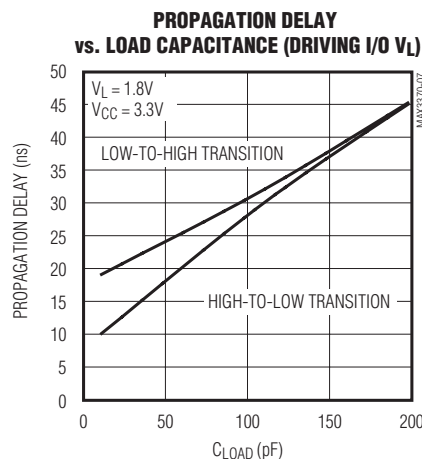
(Driving I/O V_L rail-to-rail, $R_L = 1M\Omega$, $T_A = +25^\circ\text{C}$, unless otherwise noted.)



1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

Typical Operating Characteristics (continued)

(Driving I/O V_L rail-to-rail, $R_L = 1M\Omega$, $T_A = +25^\circ C$, unless otherwise noted.)



MAX3370/MAX3371

1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

Pin Description

PIN			NAME	FUNCTION
MAX3370		MAX3371 (SC70-6 AND μDFN-6)		
(SC70-5)	(μDFN-6)			
1	1	1	V _L	Logic Supply Voltage
2	2	2	GND	Ground
3	3	3	I/O V _L	Input/Output Referred to V _L
4	4	4	I/O V _{CC}	Input/Output Referred to V _{CC}
5	6	6	V _{CC}	Power-Supply Voltage
—	—	5	$\overline{\text{SHDN}}$	Shutdown. A high turns on the device. A low shuts down the device. I/O V _{CC} and I/O V _L are high impedance in shutdown.
—	5	—	N.C.	No Connection

Detailed Description

The MAX3370/MAX3371 provide the necessary level translation to allow data transfer in a multivoltage system. These devices transmit data between an I/O pin referenced to V_{CC} and an I/O pin referenced to V_L. The V_{CC} supply voltage range is from +2.5V to +5.5V, and the V_L supply voltage range is between +1.6V and +5.5V. The MAX3371 features a shutdown mode in which I/O V_{CC} and I/O V_L are placed in a high-impedance state and supply current drops to 1 μ A.

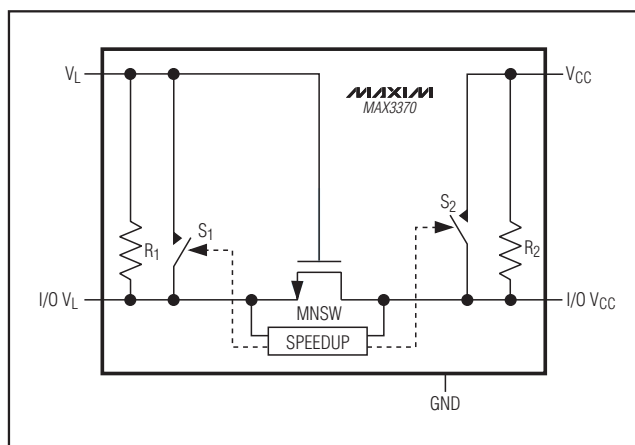
The MAX3370/MAX3371 are bidirectional level shifters allowing data transfer from the V_{CC} side to the V_L side, and from the V_L side to the V_{CC} side. Both devices operate at speeds up to 2Mbps with an active driver and up to 500kbps with an open-drain driver.

Level Translation

The MAX3370/MAX3371 provide bidirectional level translation between I/O pins referred to V_{CC} and V_L. I/O V_{CC} and I/O V_L are internally pulled up to their respective power-supply rails through 10k Ω resistors. V_{CC} must be between +2.5V and +5.5V, and V_L must be between +1.6V and +5.5V. For proper operation, V_L can not exceed V_{CC}.

The MAX3370/MAX3371 can operate at data rates up to 2Mbps when driven by an active (push-pull) driver with a 10pF load, 1Mbps when driven by an active driver with a 50pF load, or 500kbps when driven by an open-drain driver with a 30pF load. The internal pullups allow these devices to be driven by open-drain drivers.

Functional Diagram



MAX3371 Shutdown Mode

The MAX3371 enters a low-power shutdown mode when $\overline{\text{SHDN}}$ is driven low. Connect $\overline{\text{SHDN}}$ to V_L or drive high for normal operation. Activating shutdown mode disconnects the internal 10k Ω pullup resistors on I/O V_{CC} and I/O V_L. As a result, the supply current decreases to < 1 μ A, and the I/O lines are high impedance. The high impedance I/O lines in shutdown allow use in a multidrop network. When in shutdown, I/O V_L can be driven to V_L and I/O V_{CC} can be driven to V_{CC}.

1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

Speed-Up

The speed-up circuit is a one-shot generator that helps the rise time of the output waveform in the low-to-high transition. When triggered, switches S_1 and S_2 turn on for 320ns to pull up I/O V_L and I/O V_{CC} . This greatly reduces the rise time and propagation delay for the low-to-high transition as well as improves the duty cycle (closer to 50% for an ideal square-wave input). See the scope plots in the *Typical Operating Characteristics* for the speed-up circuitry in operation.

Applications Information

Power-Supply Decoupling

To reduce ripple and the chance of transmitting incorrect data, decouple V_{CC} and V_L to ground with a 0.1 μ F capacitor as close to the device as possible.

I²C Level Translation

The MAX3370/MAX3371 are ideal for level translation between a low-voltage ASIC and an I²C device. The devices' bidirectional natures allow their use in the data line of I²C communications. A typical application is interfacing a low-voltage microprocessor to a 3V or 5V D/A converter, such as the MAX517.

The I/O lines on the MAX3370/MAX3371 are bidirectional, can be level-shifted up to +5.5V, and contain internal 10k Ω pullup resistors to allow open-drain driving (see the *Typical Operating Circuit*).

Push-Pull vs. Open-Drain Driving

The MAX3370/MAX3371 I/O pins can be driven by a push-pull or open-drain device. When using a push-pull driver, the MAX3370/MAX3371 operate up to 2Mbps with a 10pF load or 1Mbps with a 50pF load. The internal pullup resistors on the I/O pins allow use with open-drain devices. The MAX3370/MAX3371 operate up to 500kbps with a 30pF load when driven by an open-drain device.

Data rates higher than those listed in the *Electrical Characteristics* table can be achieved. The maximum data rate is limited to 3Mbps by the speed-up circuitry.

Unidirectional vs. Bidirectional Level Translator

The MAX3370/MAX3371 may also be used to translate unidirectional signals without signal inversion. The devices provide the smallest solution (SC70 package) for unidirectional level translation without inversion.

Chip Information

PROCESS: BiCMOS

Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
5 SC70	X5+1	21-0076
6 SC70	X6SN+1	21-0077
6 μ DFN	L611+2	21-0147

1 μ A, 2Mbps, Low-Voltage Level Translators in SC70 and μ DFN

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	10/00	Initial release	—
3	5/09	Updated <i>Ordering Information</i> , style edits.	1, 5, 8, 9, 11

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

10 **Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600**

© 2009 Maxim Integrated Products

Maxim is a registered trademark of Maxim Integrated Products, Inc.